

Atmel AT24C32D and Atmel AT24C64D

I²C Automotive Temperature Serial EEPROM 32K (4096 x 8), 64K (8192 x 8)

PRELIMINARY DATASHEET

Features

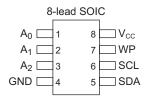
- Standard-voltage operation
 - $V_{CC} = 2.5V \text{ to } 5.5V$
- Automotive temperature range –40°C to 125°C
- Internally organized 4096 x 8 (32K), 8192 x 8 (64K)
- 2-wire serial interface compatible with I²C
- Schmitt Trigger, filtered inputs for noise suppression
- Bidirectional data transfer protocol
- 400kHz compatibility
- Write protect pin for hardware data protection
- 32-byte page Write modes
- Partial page Writes are allowed
- Self-timed write cycle (5ms max)
- High-reliability
 - Endurance: 1 million write cycles
 - Data retention: 100 years
- 8-lead JEDEC SOIC and 8-lead TSSOP packages

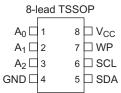
Description

The Atmel® AT24C32D/64D provides 32768/65536 bits of Serial Electrically Erasable and Programmable Read-Only Memory (EEPROM) organized as 4096/8192 words of eight bits each. The device is optimized for use in many automotive applications where low-power and low-voltage operation are essential. The AT24C32D/64D is available in space-saving 8-lead JEDEC SOIC and 8-lead TSSOP packages and is accessed via a 2-wire serial interface. This device operates from 2.5V to 5.5V.

Figure 1. Pin Configurations

Pin Name	Function
SDA	Serial Data
SCL	Serial Clock Input
WP	Write Protect
A ₀ - A ₂	Address Inputs



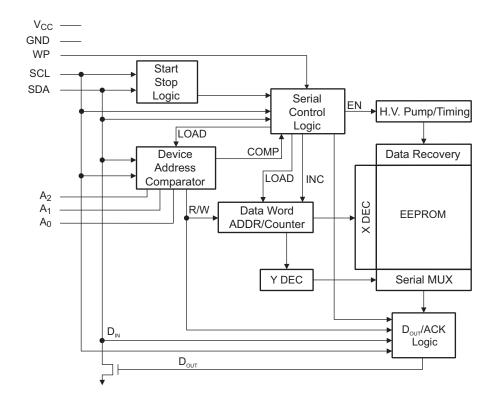


1. Absolute Maximum Ratings*

Operating Temperature
Storage Temperature65°C to +150°C
Voltage on any pin with respect to ground1.0V to +7.0V
Maximum Operating Voltage 6.25V
DC Output Current 5.0mA

*Notice: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2. Block Diagram





3. Pin Description

Serial Clock (SCL): The SCL input is used to positive edge clock data into each EEPROM device and negative edge clock data out of each device.

Serial Data (SDA): The SDA pin is bi-directional for serial data transfer. This pin is open-drain driven and may be wire-ORed with any number of other open-drain or open-collector devices.

Device Addresses (A₂, A₁, A₀): The A₂, A₁, and A₀ pins are device address inputs that are hardwired or left not connected for hardware compatibility with other Atmel AT24CXX devices. When the pins are hardwired, as many as eight 32K/64K devices may be addressed on a single bus system (device addressing is discussed in detail in Section 6., Device Addressing). If the pins are left floating, the A₂, A₁, and A₀ pins will be internally pulled down to GND if the capacitive coupling to the circuit board V_{CC} plane is <3pF. If coupling is >3pF, Atmel recommends connecting the pin to GND.

Write Protect (WP): The AT24C32D/64D has a write protect pin that provides hardware data protection. The write protect pin allows normal read/write operations when connected to ground (GND). When the write protect pin is connected to V_{CC}, the write protection feature is enabled and operates as shown in the following table.

Table 3-1. Write Protect

WP Pin	Part of the Array Protected
Status	Atmel AT24C32D/64D
At V _{CC}	Full (32K/64K) Array
At GND	Normal Read/Write Operations



4. Memory Organization

AT24C32D/64D, 32K/64KSerial EEPROM: The 32K/64K is internally organized as 128/256 pages of 32 bytes each. Random word addressing requires a 12/13 bit data word address.

4.1 Pin Capacitance⁽¹⁾

Symbol	Test Condition	Max	Units	Conditions
C _{I/O}	Input/Output Capacitance (SDA)	8	pF	V _{I/O} = 0V
C _{IN}	Input Capacitance (SCL)	6	pF	V _{IN} = 0V

Note: 1. This parameter is characterized and is not 100% tested.

4.2 DC Characteristics

Applicable over recommended operating range from: T_A = -40°C to +125°C, V_{CC} = +2.5V to +5.5V (unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Units
V _{CC1}	Supply Voltage		2.5		5.5	V
I _{cc}	Supply Current V _{CC} = 5.0V	Read at 100kHz		0.4	1.0	mA
I _{cc}	Supply Current V _{CC} = 5.0V	Write at 100kHz		2.0	3.0	mA
I _{SB1}	Standby Current V _{CC} = 2.5V	$V_{IN} = V_{CC}$ or V_{SS}		1.6	4.0	μΑ
I _{SB2}	Standby Current V _{CC} = 5.0V	$V_{IN} = V_{CC}$ or V_{SS}		4.0	6.0	μΑ
ILI	Input Leakage Current	$V_{IN} = V_{CC}$ or V_{SS}		0.10	3.0	μΑ
I _{LO}	Output Leakage Current	$V_{OUT} = V_{CC} \text{ or } V_{SS}$		0.05	3.0	μΑ
V _{IL}	Input Low Level ⁽¹⁾		-0.6		V _{CC} x 0.3	V
V _{IH}	Input High Level ⁽¹⁾		V _{CC} x 0.7		V _{CC} + 0.5	V
V _{OL2}	Output Low Level V _{CC} = 3.0V	I _{OL} = 2.1mA			0.4	V
V _{OL1}	Output Low Level V _{CC} = 1.8V	I _{OL} = 0.15mA			0.2	V

Note: 1. V_{IL} min and V_{IH} max are reference only and are not tested.



4.3 AC Characteristics

Applicable over recommended operating range from T_A = -40°C to +125°C, V_{CC} = +2.5V to +5.5V, CL = 1 TTL Gate and 100pF (unless otherwise noted)

Symbol	Parameter	Min	Max	Units
f _{SCL}	Clock Frequency, SCL		400	kHz
t _{LOW}	Clock Pulse Width Low	1.2		μs
t _{HIGH}	Clock Pulse Width High	0.6		μs
t _I	Noise Suppression Time ⁽¹⁾		50	ns
t _{AA}	Clock Low to Data Out Valid	0.1	0.9	μs
t _{BUF}	Time the bus must be free before a new transmission can start ⁽²⁾	1.2		μs
t _{HD.STA}	Start Hold Time	0.6		μs
t _{SU.STA}	Start Set-up Time	0.6		μs
t _{HD.DAT}	Data In Hold Time	0		μs
t _{SU.DAT}	Data In Set-up Time	100		ns
t _R	Inputs Rise Time ⁽²⁾		300	ns
t _F	Inputs Fall Time ⁽²⁾		300	ns
t _{su.sto}	Stop Set-up Time	0.6		μs
t _{DH}	Data Out Hold Time	50		ns
t _{WR}	Write Cycle Time		5	ms
Endurance ⁽²⁾	5.0V, 25°C, Page Mode	1M		Write Cycles

Note: 1. This parameter is characterized and is not 100% tested ($T_A = 25$ °C).

2. This parameter is characterized.



5. Device Operation

Clock and Data Transitions: The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low time periods (see Figure 5-4 on page 7). Data changes during SCL high periods will indicate a start or stop condition as defined below.

Start Condition: A high-to-low transition of SDA with SCL high is a start condition which must precede any other command (see Figure 5-5 on page 7).

Stop Condition: A low-to-high transition of SDA with SCL high is a stop condition. After a read sequence, the stop command will place the EEPROM in a standby power mode (see Figure 5-5 on page 7).

Acknowledge: All addresses and data words are serially transmitted to and from the EEPROM in 8-bit words. The EEPROM sends a "0" to acknowledge that it has received each word. This happens during the ninth clock cycle.

Standby Mode: The AT24C32D/64D features a low-power standby mode which is enabled:

- Upon Power-up
- After the receipt of the stop bit and the completion of any internal operations

Memory Reset: After an interruption in protocol, power loss or system reset, any 2-wire part can be reset by following these steps:

- 1. Clock up to nine cycles
- 2. Look for SDA high in each cycle while SCL is high
- 3. Create a start condition

Figure 5-1. Memory Reset

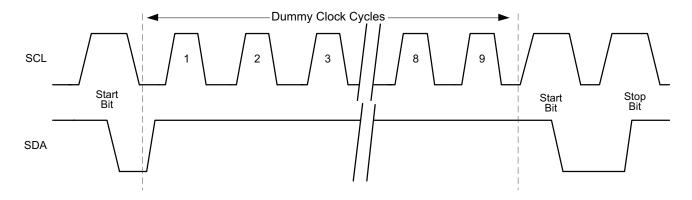


Figure 5-2. Bus Timing

SCL: Serial Clock, SDA: Serial Data I/O

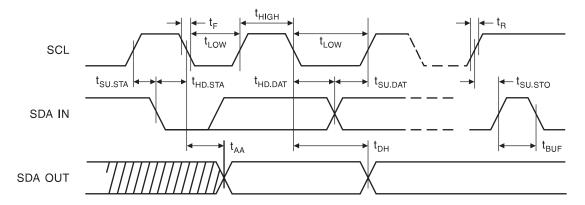
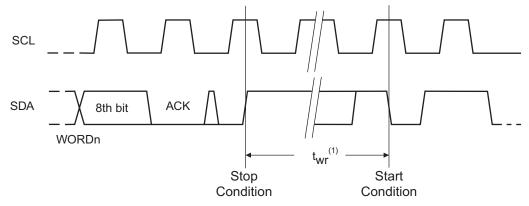




Figure 5-3. Write Cycle Timing

SCL: Serial Clock, SDA: Serial Data I/O



Note: 1. The write cycle time t_{WR} is the time from a valid stop condition of a write sequence to the end of the internal clear/write cycle.

Figure 5-4. Data Validity

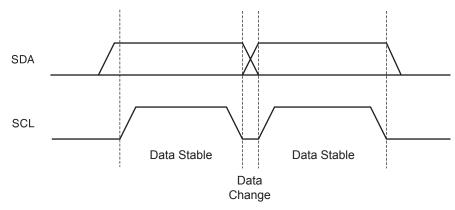


Figure 5-5. Start and Stop Definition

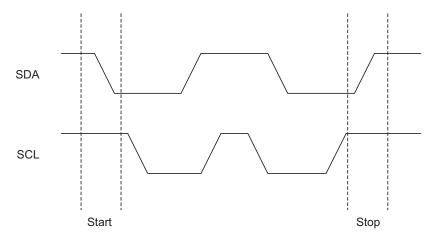
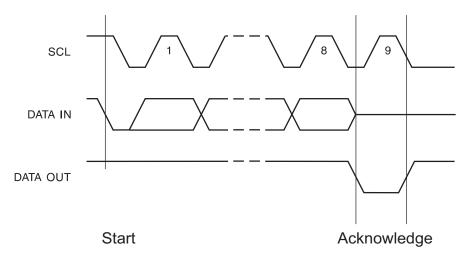




Figure 5-6. Output Acknowledge



6. Device Addressing

The 32K/64K EEPROM requires an 8-bit device address word following a start condition to enable the chip for a read or write operation (see Figure 8-1 on page 9).

The device address word consists of a mandatory "1", "0" sequence for the first four most significant bits as shown. This is common to all the Serial EEPROM devices.

The 32K/64K uses the three device address bits, A2, A1, and A0, to allow as many as eight devices on the same bus. These bits must compare to their corresponding hardwired input pins. The A_2 , A_1 , and A_0 pins use an internal proprietary circuit that biases them to a logic low condition if the pins are allowed to float.

The eighth bit of the device address is the Read/Write operation select bit. A read operation is initiated if this bit is high and a Write operation is initiated if this bit is low.

If the device address meets the requirements listed above, the device will acknowledge with a zero by pulling the SDA signal low. If the comparison is not made, the device will return to a standby state and the SDA signal will float high.

7. Write Operations

Byte Write: A Write operation requires an 8-bit data word address following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a "0" and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will output a "0" and the addressing device, such as a microcontroller, must terminate the write sequence with a stop condition. At this time the EEPROM enters an internally timed write cycle, t_{WR}, to the nonvolatile memory. All inputs are disabled during this Write cycle and the EEPROM will not respond until the Write is complete (see Figure 8-2 on page 9).

Page Write: The 32K/64K EEPROM is capable of 32-byte page writes.

A Page Write is initiated the same as a Byte Write, but the microcontroller does not send a stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the microcontroller can transmit up to thirty-one more data words. The EEPROM will respond with a "0" after each data word received. The microcontroller must terminate the Page Write sequence with a Stop condition (see Figure 8-3 on page 10).

The data word address lower five bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than thirty-one data words are transmitted to the EEPROM, the data word address will "roll over" and previous data will be overwritten.



Acknowledge Polling: Once the internally timed Write cycle has started and the EEPROM inputs are disabled, Acknowledge Polling can be initiated. This involves sending a Start condition followed by the device address word. The Read/Write bit is representative of the operation desired. Only if the internal Write cycle has completed will the EEPROM respond with a "0", allowing the Read or Write sequence to continue.

8. Read Operations

Read operations are initiated the same way as Write operations with the exception that the Read/Write select bit in the device address word is set to "1". There are three Read operations: Current Address Read, Random Address Read, and Sequential Read.

Current Address Read: The internal data word address counter maintains the last address accessed during the last Read or Write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address "roll over" during Read is from the last byte of the last memory page to the first byte of the first page. The address "roll over" during Write is from the last byte of the current page to the first byte of the same page.

Once the device address with the Read/Write select bit set to "1" is clocked in and acknowledged by the EEPROM, the current address data word is serially clocked out. The microcontroller does not respond with an input "0" but does generate a following Stop condition (see Figure 8-4 on page 10).

Random Read: A Random Read requires a "dummy" byte Write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the EEPROM, the microcontroller must generate another Start condition. The microcontroller now initiates a current address read by sending a device address with the Read/Write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a "0" but does generate a following Stop condition (see Figure 8-5 on page 10).

Sequential Read: Sequential Reads are initiated by either a Current Address Read or a Random Address Read. After the microcontroller receives a data word, it responds with an acknowledge. As long as the EEPROM receives an acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will "roll over" and the Sequential Read will continue. The Sequential Read operation is terminated when the microcontroller does not send an acknowledge (pull the SDA signal low), but does generate the Stop condition. (see Figure 8-6 on page 10).

Figure 8-1. Device Address

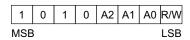
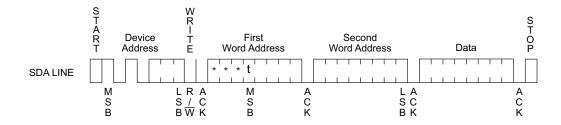


Figure 8-2. Byte Write

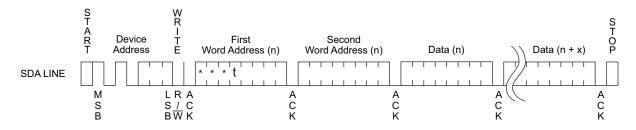


Notes: 1. * = Don't care bits

2. t = Don't care bit for Atmel AT24C32D



Figure 8-3. Page Write



Notes: 1. * = Don't care bits

2. t = Don't care bit for Atmel AT24C32D

Figure 8-4. Current Address Read

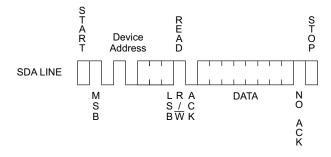
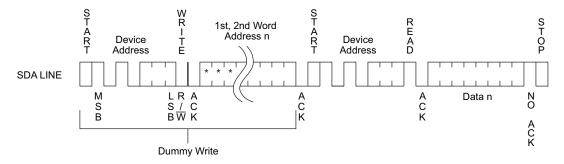
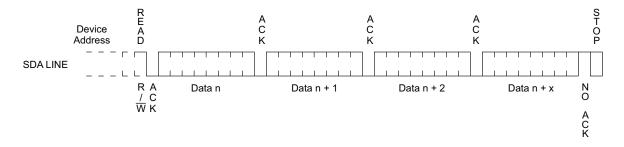


Figure 8-5. Random Read



Note: 1. * = Don't care bits

Figure 8-6. Sequential Read





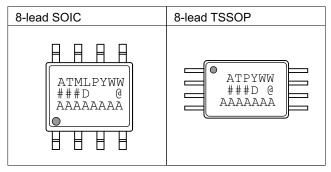
8.1 Power Recommendation

The device internal POR (power-on reset) threshold is just below the minimum operating voltage of the device. Power shall rise monotonically from 0.0Vdc to full V_{CC} in less than 1ms. Hold at full V_{CC} for at least 100µs before the first operation. Power shall drop from full V_{CC} to 0.0Vdc in less than 1ms. Power dropping to a non-zero level and then slowly going to zero is *not* recommended. Power shall remain off (0.0Vdc) for 0.5s minimum. Please consult Atmel if your power conditions do not meet the above recommendations.



9. Product Markings

AT24C32D and AT24C64D: Package Marking Information



Note 1: O designates pin 1

Note 2: Package drawings are not to scale

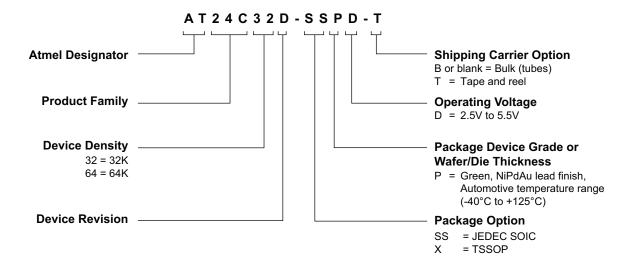
Catalog Nu	ımber Trunca	tion			
AT24C32D				Truncation Code ###: 32D	
AT24C64D				Truncation Code ###: 64D	
Date Code	s				Voltages
Y = Year		M = Month		WW = Work Week of Assembly	D: 2.5V min
2: 2012	6: 2016	A: January		02: Week 2	
3: 2013	7: 2017	B: Februar	V	04: Week 4	
4: 2014	8: 2018		•		
5: 2015	9: 2019	L: Decemb	er	52: Week 52	
Country of Assembly L		Lot Nu	mber	Grade/Lead Finish Material	
@ = Country of Assembly		AAA/	A = Atmel Wafer Lot Number	P: Automotive/NiPdAu	
Trace Code Atmel Truncation					Atmel Truncation
XX = Trace Code (Atmel Lot Numbers Corresp Example: AA, AB YZ, ZZ			orrespon	d to Code)	AT: Atmel ATM: Atmel ATML: Atmel

3/13/12

	TITLE	DRAWING NO.	REV.
Package Mark Contact: DL-CSO-Assy_eng@atmel.com	24C32-64DAM, AT24C32D and AT24C64D Automotive Package Marking Information	24C32-64DAM	В



10. Ordering Code Details





Ordering Code Information 11.

11.1 **Atmel AT24C32D Ordering Information**

Atmel Ordering Code	Package	Voltage	Operation Range
AT24C32D-SSPD	901		NiPdAu
AT24C32D-SSPD-T ⁽¹⁾	8S1	2.5V to 5.5V	Lead-free/Halogen-free
AT24C32D-XPD	8X	2.50 (0 5.50	Automotive Temperature (-40°C to 125°C)
AT24C32D-XPD-T ⁽¹⁾	0/		(=40 C to 123 C)

- Note: 1. Tape and reel delivery
 - SOIC 4k/reel
 - TSSOP 5k/reel

	Package Type
8S1	8-lead, 0.150" wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
8X	8-lead, 0.170" wide, Thin Shrink Small Outline (TSSOP)



11.2 Atmel AT24C64D Ordering Information

Atmel Ordering Code	Package		Operation Range
AT24C64D-SSPD	8S1		NiPdAu
AT24C64D-SSPD-T ⁽¹⁾	631	2.5V to 5.5V	Lead-free/Halogen-free
AT24C64D-XPD	8X	2.50 (0 5.50	Automotive Temperature (-40°C to 125°C)
AT24C64D-XPD-T ⁽¹⁾	0.7		(=40 C to 125 C)

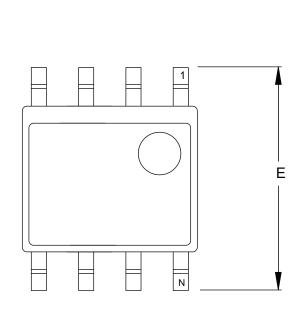
- Note: 1. Tape and reel delivery
 - SOIC 4k/reel
 - TSSOP 5k/reel

	Package Type
8S1	8-lead, 0.150" wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
8X	8-lead, 0.170" wide, Thin Shrink Small Outline (TSSOP)

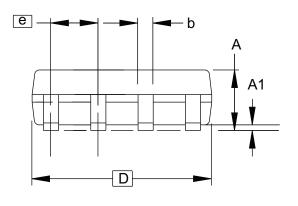


12. Packaging Information

12.1 8S1 — 8-lead JEDEC SOIC

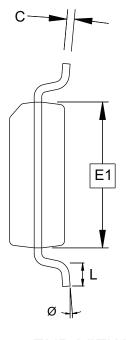


TOP VIEW



SIDE VIEW

Notes: This drawing is for general information only. Refer to JEDEC Drawing MS-012, Variation AA for proper dimensions, tolerances, datums, etc.



END VIEW

COMMON DIMENSIONS (Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	1.35	_	1.75	
A1	0.10	-	0.25	
b	0.31	_	0.51	
С	0.17	_	0.25	
D	4.80	_	5.05	
E1	3.81	_	3.99	
Е	5.79	_	6.20	
е	1.27 BSC			
L	0.40	_	1.27	
Ø	0°	_	8°	

6/22/11



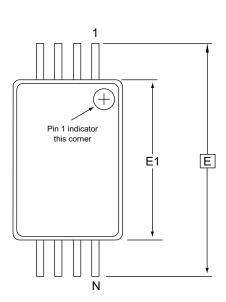
Package Drawing Contact: packagedrawings@atmel.com

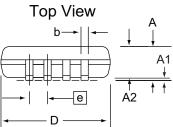
TITLE8S1, 8-lead (0.150" Wide Body), Plastic Gull Wing Small Outline (JEDEC SOIC)

GPC DRAWING NO. REV.
SWB 8S1 G



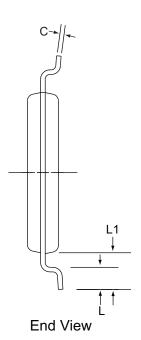
8X — 8-lead TSSOP 12.2







- Notes: 1. This drawing is for general information only. Refer to JEDEC Drawing MO-153, Variation AA, for proper dimensions, tolerances, datums, etc.
 - 2. Dimension D does not include mold Flash, protrusions or gate burrs. Mold Flash, protrusions and gate burrs shall not exceed 0.15mm (0.006in) per side.
 - 3. Dimension E1 does not include inter-lead Flash or protrusions. Inter-lead Flash and protrusions shall not exceed 0.25mm (0.010in) per side.
 - 4. Dimension b does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08mm total in excess of the b dimension at maximum material condition. Dambar cannot be located on the lower radius of the foot. Minimum space between protrusion and adjacent lead is 0.07mm.
 - 5. Dimension D and E1 to be determined at Datum Plane H.



COMMON DIMENSIONS (Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	-	-	1.20	
A1	0.05	-	0.15	
A2	0.80	1.00	1.05	
D	2.90	3.00	3.10	2, 5
Е	6.40 BSC			
E1	4.30	4.40	4.50	3, 5
b	0.19	_	0.30	4
е	0.65 BSC			
L	0.45	0.60	0.75	
L1	1.00 REF			
С		0.09	-	0.20

6/22/11



Package Drawing Contact: packagedrawings@atmel.com

TITLE 8X, 8-lead 4.4mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)

GPC	DRAWING NO.	REV.	
TNR	8X	D	



13. Revision History

Ooc. Rev.	Date	Comments
A0088	03/2012	Initial document release





Enabling Unlimited Possibilities®

Atmel Corporation

2325 Orchard Parkway San Jose, CA 95131

USA

Tel: (+1) (408) 441-0311 **Fax:** (+1) (408) 487-2600

www.atmel.com

Atmel Asia Limited

Unit 01-5 & 16, 19F

BEA Tower, Millennium City 5

418 Kwun Tong Roa

Kwun Tong, Kowloon

HONG KONG

Tel: (+852) 2245-6100 **Fax:** (+852) 2722-1369

Atmel Munich GmbH

Business Campus

Parkring 4

D-85748 Garching b. Munich

GERMANY

Tel: (+49) 89-31970-0

Fax: (+49) 89-3194621

Atmel Japan G.K.

16F Shin-Osaki Kangyo Bldg

1-6-4 Osaki, Shinagawa-ku

Tokyo 141-0032

JAPAN

Tel: (+81) (3) 6417-0300

Fax: (+81) (3) 6417-0370

© 2012 Atmel Corporation. All rights reserved. / Rev.: 8800A-SEEPR-3/12

Atmel[®], Atmel logo and combinations thereof, Enabling Unlimited Possibilities[®], and others are registered trademarks or trademarks of Atmel Corporation or its subsidiaries. Other terms and product names may be trademarks of others.

Disclaimer: The information in this document is provided in connection with Atmel products. No license, express or implied, by estoppel or otherwise, to any intellectual property right is granted by this document or in connection with the sale of Atmel products. EXCEPT AS SET FORTH IN THE ATMEL TERMS AND CONDITIONS OF SALES LOCATED ON THE ATMEL WEBSITE, ATMEL ASSUMES NO LIABILITY WHATSOEVER AND DISCLAIMS ANY EXPRESS, IMPLIED OR STATUTORY WARRANTY RELATING TO ITS PRODUCTS INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTY OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT. IN NO EVENT SHALL ATMEL BE LIABLE FOR ANY DIRECT, INDIRECT, CONSEQUENTIAL, PUNITIVE, SPECIAL OR INCIDENTAL DAMAGES (INCLUDING, WITHOUT LIMITATION, DAMAGES FOR LOSS AND PROFITS, BUSINESS INTERRUPTION, OR LOSS OF INFORMATION) ARISING OUT OF THE USE OR INABILITY TO USE THIS DOCUMENT, EVEN IF ATMEL HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES. Atmel makes no representations or warranties with respect to the accuracy or completeness of this document and reserves the right to make changes to specifications and products descriptions at any time without notice. Atmel does not make any commitment to update the information contained herein. Unless specifically provided otherwise, Atmel products are not suitable for, and shall not be used in, automotive applications. Atmel products are not intended, authorized, or warranted for use as components in applications intended to support or sustain life.